

# SINGLE-ENDED OUTPUT SILICON OSCILLATOR

#### Features

- Quartz-free, MEMS-free, and PLL-free all-silicon oscillator Footprint compatible with industry-
- Any output frequencies from 0.9 to 200 MHz
- Short lead times
- Excellent temperature stability (±20 ppm)
- Highly reliable startup and operation
- High immunity to shock and vibration
- Low jitter: <1.5 ps rms
- 0 to 85 °C operation includes 10-year aging in hot environments
- standard 3.2 x 5.0 mm XOs
- CMOS and SSTL versions available
- Driver stopped, tri-state, or powerdown operation
- **RoHS** compliant
- 1.8, 2.5, or 3.3 V options
- Low power
- More than 10x better fit rate than competing crystal solutions



#### **Specifications**

Parameters	Parameters Condition		Тур	Max	Units
Frequency Range		0.9	—	200	MHz
	Temperature stability, 0 to +70 °C	_	±10	_	ppm
Francisco Otabilita	Temperature stability, 0 to +85 °C	_	±20		ppm
Frequency Stability	Total stability, 0 to +70 °C operation <sup>1</sup>	_	-	±150	ppm
	Total stability, 0 to +85 °C operation <sup>2</sup>	_	-	±250	ppm
	Commercial	0	—	70	°C
Operating Temperature	Extended commercial	0	—	85	°C
Storage Temperature		-55	—	+125	°C
	1.8 V option	1.71	—	1.98	V
Supply Voltage	2.5 V option	2.25		2.75	V
	3.3 V option	2.97	—	3.63	V

#### Notes:

1. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, first-year aging at 25 °C, shock, vibration, and one solder reflow.

2. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, ten-vear aging at 85 °C, shock, vibration, and one solder reflow.

3. See "AN409: Output Termination Options for the Si500S and Si500D Silicon Oscillators" for further details regarding output clock termination recommendations.

**4.**  $V_{TT} = .5 \times V_{DD}$ .

5. V<sub>TT</sub> = .45 x V<sub>DD</sub>.

Parameters	Condition	Min	Тур	Max	Units	
	1.8 V option, 40 pF, 40 MHz, CMOS	_	13.9	16	mA	
	1.8 V option, 10 pF, 200 MHz, CMOS	—	16.7	19	mA	
	2.5 V option, 40 pF, 40 MHz, CMOS	—	15.8	18	mA	
	2.5 V option, 10 pF, 200 MHz, CMOS	—	19.3	22	mA	
	3.3 V option, 40 pF, 40 MHz, CMOS	—	17.7	20	mA	
Supply Current	3.3 V option, 10 pF, 200 MHz, CMOS	—	21.5	24	mA	
Supply Culterit	SSTL-3.3, 200 MHz	—	18.1	20.2	mA	
	SSTL-2.5, 200 MHz		18.0	19.7	mA	
	SSTL-1.8, 200 MHz		16.8	18.7	mA	
	Output Stopped, CMOS	—	11.8	13.1	mA	
	Tri-State	—	9.7	10.7	mA	
	Powerdown	—	1.0	1.9	mA	
Output Symmetry	0.5 x V <sub>DD</sub>	46 – 13 ns/T <sub>CLK</sub>	_	54 + 13 ns/T <sub>CLK</sub>	%	
Rise and Fall Times <sup>3</sup>	CMOS, $C_L$ = 15 pF measured from 20 to 80% of $V_{DD}$	_	1.4	2.0	ns	
	SSTL	—	—	0.6	ns	
CMOS Output Voltage	V <sub>OH</sub> , sourcing 9 mA	V <sub>DD</sub> – 0.5	—	—	V	
emee oupur vonage	V <sub>OL</sub> , sinking 9 mA	—	—	0.5	V	
SSTL-1.8 Output Voltage <sup>4</sup>	V <sub>OH</sub>	V <sub>TT</sub> + 0.375	—	—	V	
COTE 1.0 Output Voltage	V <sub>OL</sub>	—	—	V <sub>TT</sub> – 0.375	v	
SSTL-2.5 Output Voltage <sup>4</sup>	V <sub>OH</sub>	V <sub>TT</sub> + 0.48	—	—	V	
	V <sub>OL</sub>	—	—	V <sub>TT</sub> – 0.48	v	
SSTL-3.3 Output Voltage <sup>5</sup>	V <sub>OH</sub>	V <sub>TT</sub> + 0.48	—	—	V	
COTE 0.0 Calput Voltage	V <sub>OL</sub>	—	—	V <sub>TT</sub> – 0.48	v	
Powerup Time	From time V <sub>DD</sub> crosses min spec supply	_	_	2	ms	
OE Deassertion to Clk Stop		_	_	250 + 3 x T <sub>CLK</sub>	ns	
Return from Output Driver Stopped Mode		_	_	250 + 3 x T <sub>CLK</sub>	ns	
Return from Tri-State Time			—	12 + 3 x T <sub>CLK</sub>	μs	
Return from Powerdown Time		—	—	2	ms	
Period Jitter (1-sigma)	SSTL <sup>3</sup>	_	1	2	ps RMS	
Integrated Phase Jitter	1 MHz – 0.4 x F <sub>OUT</sub> , SSTL or CMOS and C <sub>L</sub> $\leq$ 7 pF, F <sub>OUT</sub> > 2.5 MHz	_	0.7	1.5	ps RMS	

Notes:

1. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, first-year aging at 25 °C, shock, vibration, and one solder reflow.

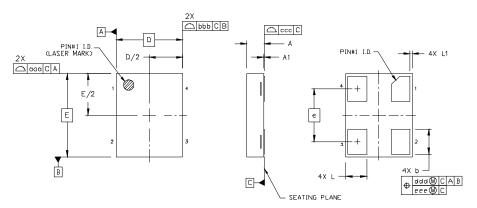
2. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, ten-year aging at 85 °C, shock, vibration, and one solder reflow.

3. See "AN409: Output Termination Options for the Si500S and Si500D Silicon Oscillators" for further details regarding output clock termination recommendations.

4. V<sub>TT</sub> = .5 x V<sub>DD</sub>.
5. V<sub>TT</sub> = .45 x V<sub>DD</sub>.



## **Package Specifications**



#### Table 1. Package Diagram Dimensions (mm)

Dimension	Min	Nom	Max	
А	0.80	0.85	0.90	
A1	0.00	0.00 0.03		
b	1.15	1.25		
D	3.20 BSC			
е	2.54 BSC			
E	4.00 BSC			
L	0.95 1.00 1.05			

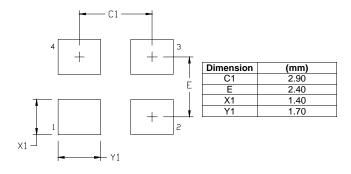
Dimension	Min	Nom	Max
L1	0.00	0.05	0.10
aaa			0.10
bbb			0.10
CCC			0.08
ddd			0.10
eee			0.05

## **Table 2. Pad Connections**

1	OE
2	GND
3	Output
4	VDD

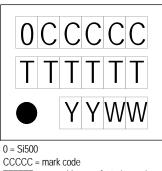
#### Table 3. Tri-State/Powerdown/Driver Stopped Function on OE (3rd Option Code)

	Α	В	С	D	Е	F
Open	Active	Active	Active	Active	Active	Active
1 Level	Active	Tri- State	Active	Power- down	Active	Driver Stopped
0 Level	Tri- State	Active	Power- down	Active	Driver Stopped	Active

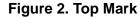


#### Figure 1. Recommended Land Pattern





CCCCC = mark code TTTTTT = assembly manufacturing code YY = year WW = work week

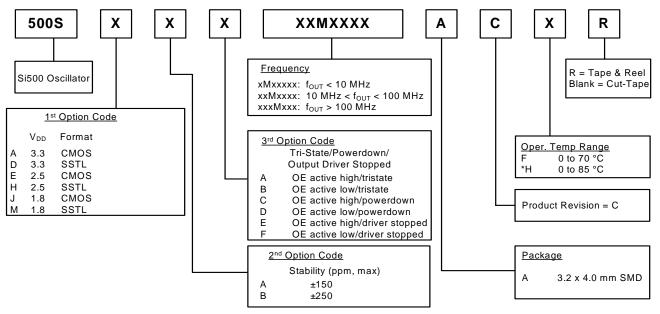


### **Environmental Compliance**

Parameter	Conditions/Test Method		
Mechanical Shock	MIL-STD-883, Method 2002.4		
Mechanical Vibration	MIL-STD-883, Method 2007.3 A		
Resistance to Soldering Heat	MIL-STD-202, 260 C° for 8 seconds		
Solderability	MIL-STD-883, Method 2003.8		
Damp Heat	IEC 68-2-3		
Moisture Sensitivity Level	J-STD-020, MSL 3		

#### **Ordering Information**

The Si500S supports a variety of options including frequency, output format, supply voltage, and tristate/powerdown/output driver stopped mode. Specific device configurations are programmed into the Si500S at time of shipment. Configurations are specified using the figure below. Silicon Labs provides a web-based part number utility that can be used to simplify part number configuration. Refer to www.silabs.com/SiliconXOPartnumber to access this tool. The Si500S silicon oscillator is supplied in a ROHScompliant, 4-pad, 3.2 x 4.0 mm package. Tape and reel packaging is available as an ordering option.



\*Note: Only <u>+</u>250 ppm is supported.



# DOCUMENT CHANGE LIST

# **Revision 0.3 to Revision 0.4**

- Revision B to Revision C updated in Ordering Information
- 0 to 85 C° Operating Temperature Range option added
- Multiple CMOS output format codes removed

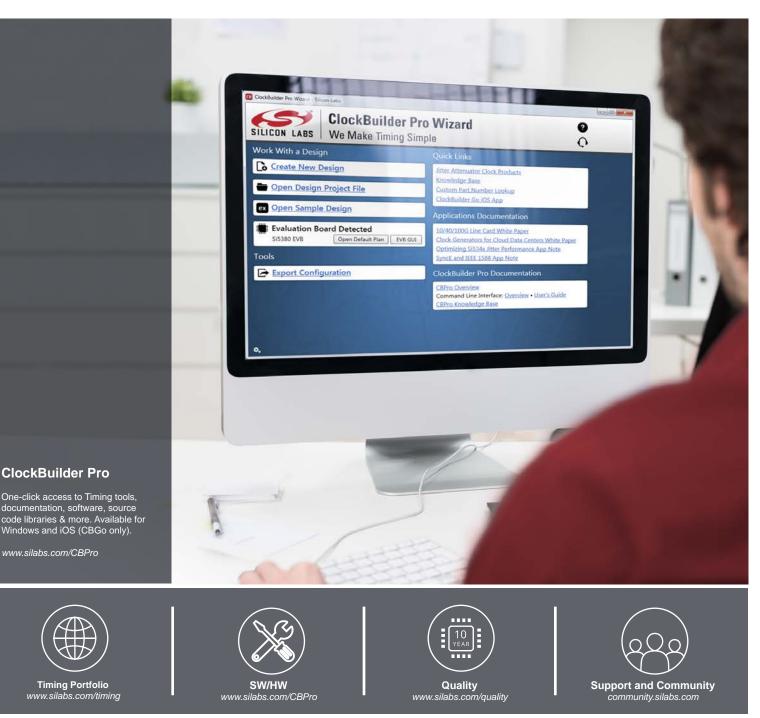
## **Revision 0.4 to Revision 1.0**

- Clarified SSTL specifications.
- Revised CMOS supply current max values .

## **Revision 1.0 to Revision 1.1**

- Updated Ordering information for ±250 ppm from 0 to +85 °C.
- Updated jitter from 1.5 ps to 1.5 ps rms.
- Updated operating temperature to include extended commercial at 0 to +85 °C.





#### Disclaimer

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